

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

5LP01M-

P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|--------|------------------------|-------------|------|
| Drain-to-Source Voltage | VDSS | | -50 | V |
| Gate-to-Source Voltage | VGSS | | ±10 | V |
| Drain Current (DC) | ID | | -0.07 | Α |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | -0.28 | Α |
| Allowable Power Dissipation | PD | | 0.15 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | 1.1 |
|--|-----------------------|---|---------|-----|------|------|
| | | | min | typ | max | Unit |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | ID=-1mA, VGS=0V | -50 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | VDS=-50V, VGS=0V | | | -1 | μΑ |
| Gate-to-Source Leakage Current | IGSS | V _{GS} =±8V, V _{DS} =0V | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | V _{DS} =-10V, I _D =-100μA | -0.4 | | -1.4 | V |
| Forward Transfer Admittance | yfs | V _{DS} =-10V, I _D =-40mA | 70 | 100 | | mS |
| Static Drain-to-Source On-State Resistance | R _{DS} (on)1 | ID=-40mA, VGS=-4V | | 18 | 23 | Ω |
| | R _{DS} (on)2 | ID=-20mA, VGS=-2.5V | | 20 | 28 | Ω |
| | RDS(on)3 | ID=-5mA, VGS=-1.5V | | 30 | 60 | Ω |
| Input Capacitance | Ciss | V _{DS} =-10V, f=1MHz | | 7.4 | | pF |
| Output Capacitance | Coss | V _{DS} =-10V, f=1MHz | | 4.2 | | pF |
| Reverse Transfer Capacitance | Crss | VDS=-10V, f=1MHz | | 1.3 | | pF |

Marking: XB Continued on next page.

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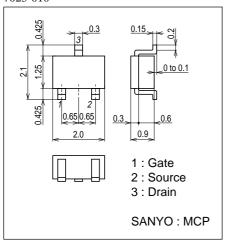
5LP01M

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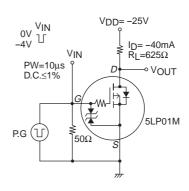
| Parameter | Cumbal | Conditions | | Ratings | | |
|-----------------------|----------------------|---|-----|---------|------|------|
| | Symbol | | min | typ | max | Unit |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit. | | 20 | | ns |
| Rise Time | t _r | See specified Test Circuit. | | 35 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | | 160 | | ns |
| Fall Time | tf | See specified Test Circuit. | | 150 | | ns |
| Total Gate Charge | Qg | V _{DS} =-10V, V _{GS} =-10V, I _D =-70mA | | 1.40 | | nC |
| Gate Source Charge | Qgs | V _{DS} =-10V, V _{GS} =-10V, I _D =-70mA | | 0.16 | | nC |
| Gate Drain Charge | Qgd | V _{DS} =-10V, V _{GS} =-10V, I _D =-70mA | | 0.23 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =-70mA, V _{GS} =0V | | -0.85 | -1.2 | V |

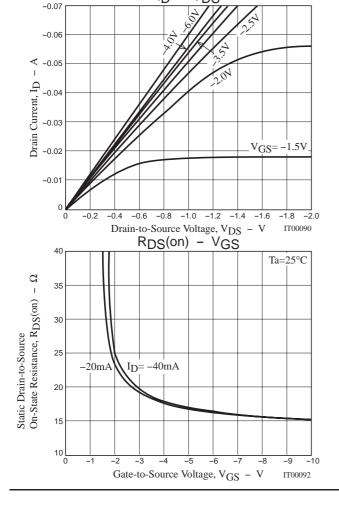
Package Dimensions

unit : mm 7023-010

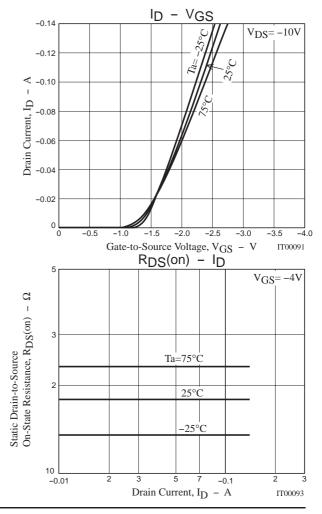


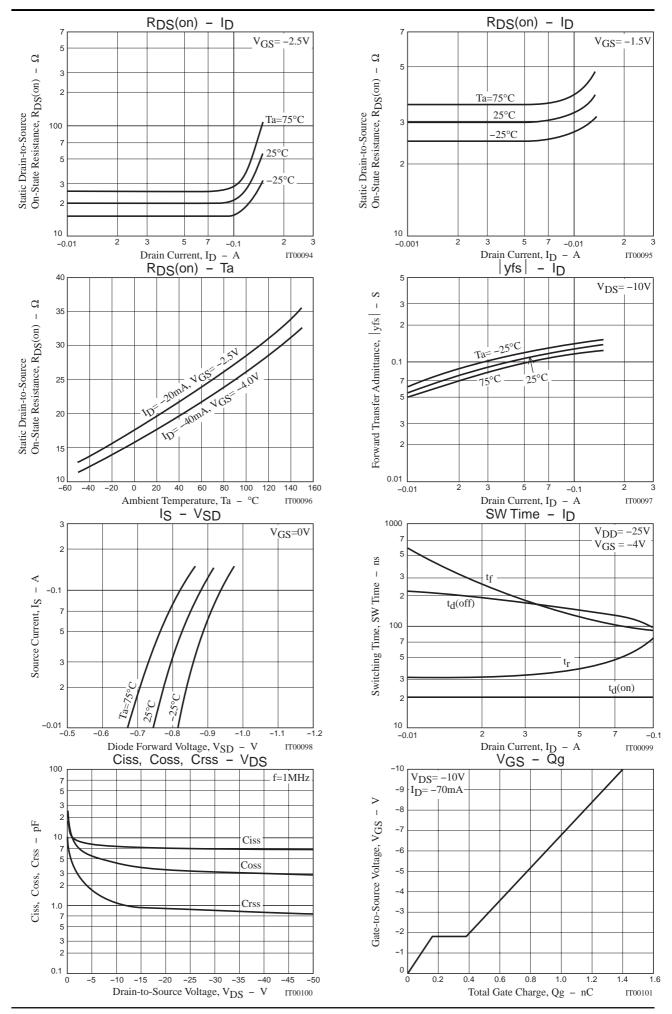
Switching Time Test Circuit

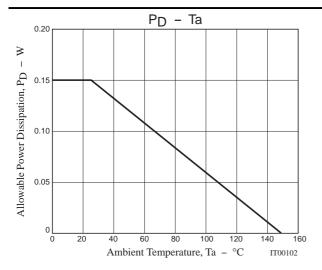




ID - VDS







Note on usage: Since the 5LP01M is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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